

20V P-Channel Enhancement Mode MOSFET

Description

The NP2301FVR uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

General Features

- ◆ $V_{DS} = -20V$, $I_D = -2.3A$
 $R_{DS(ON)}(Typ.) = 112m\Omega$ @ $V_{GS} = -4.5V$
 $R_{DS(ON)}(Typ.) = 140m\Omega$ @ $V_{GS} = -2.5V$
- ◆ High power and current handling capability
- ◆ Lead free product is acquired
- ◆ Surface mount package

Application

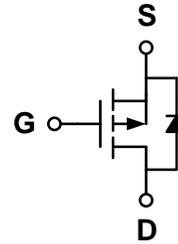
- ◆ PWM applications
- ◆ Load switch

Package

- ◆ SOT-23

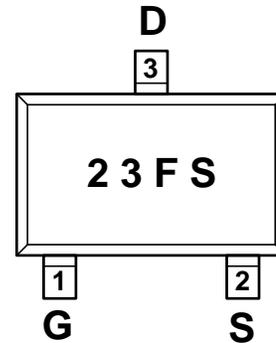


Schematic diagram



Marking and pin assignment

SOT-23
(TOP VIEW)



Ordering Information

| Part Number | Storage Temperature | Package | Devices Per Reel |
|-------------|---------------------|---------|------------------|
| HX2301A | -55°C to +150°C | SOT-23 | 3000 |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| parameter | symbol | limit | unit |
|--|----------|---------|------|
| Drain-source voltage | V_{DS} | -20 | V |
| Gate-source voltage | V_{GS} | ±12 | V |
| Drain current-continuous ^a @ $T_j = 125^\circ C$ -pulse ^b | I_D | -2.3 | A |
| | I_{DM} | -7.6 | A |
| Drain-source Diode forward current | I_S | -1.25 | A |
| Maximum power dissipation | P_D | 1 | W |
| Operating junction Temperature range | T_j | -55—150 | °C |

Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|--------------|--|------|-------|-----------|------------|
| OFF Characteristics | | | | | | |
| Drain-source breakdown voltage | BV_{DSS} | $V_{GS}=0V, I_D=-250\mu A$ | -20 | - | - | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS}=-20V, V_{GS}=0V$ | - | - | -1 | μA |
| Gate-body leakage | I_{GSS} | $V_{DS}=0V, V_{GS}=\pm 12V$ | - | - | ± 100 | nA |
| ON Characteristics | | | | | | |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$ | -0.5 | -0.7 | -1.2 | V |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}=-4.5V, I_D=-1.8A$ | - | 112 | 140 | m Ω |
| | | $V_{GS}=-2.5V, I_D=-1A$ | - | 140 | 165 | |
| Forward transconductance | g_{fs} | $V_{GS}=-5V, I_D=-1.8A$ | - | 5 | - | S |
| Dynamic Characteristics | | | | | | |
| Input capacitance | C_{ISS} | $V_{DS}=-10V, V_{GS}=0V$ $f=1.0MHz$ | - | 325 | - | pF |
| Output capacitance | C_{OSS} | | - | 63 | - | |
| Reverse transfer capacitance | C_{RSS} | | - | 37 | - | |
| Switching Characteristics | | | | | | |
| Turn-on delay time | $t_{D(on)}$ | $V_{DD}=-10V$ $I_D=-1A$ $V_{GEN}=-4.5V$ $R_L=10ohm$ $R_{GEN}=-60ohm$ | - | 11 | - | ns |
| Rise time | t_r | | - | 5.5 | - | |
| Turn-off delay time | $t_{D(off)}$ | | - | 22 | - | |
| Fall time | t_f | | - | 8 | - | |
| Total gate charge | Q_g | $V_{DS}=-10V, I_D=-1A$ $V_{GS}=-4.5V$ | - | 3.2 | - | nC |
| Gate-source charge | Q_{gs} | | - | 0.6 | - | |
| Gate-drain charge | Q_{gd} | | - | 0.9 | - | |
| DRAIN-SOURCE DIODE CHARACTERISTICS | | | | | | |
| Diode forward voltage | V_{SD} | $V_{GS}=0V, I_S=-1.25A$ | - | -0.81 | -1.2 | V |

Notes:

- surface mounted on FR4 board, $t \leq 10sec$
- pulse test: pulse width $\leq 300\mu s$, duty $\leq 2\%$
- guaranteed by design, not subject to production testing

Thermal Characteristics

| | | | |
|--|--------|-----|---------------|
| Thermal Resistance junction-to ambient | Rth JA | 100 | $^{\circ}C/W$ |
|--|--------|-----|---------------|

Typical Performance Characteristics

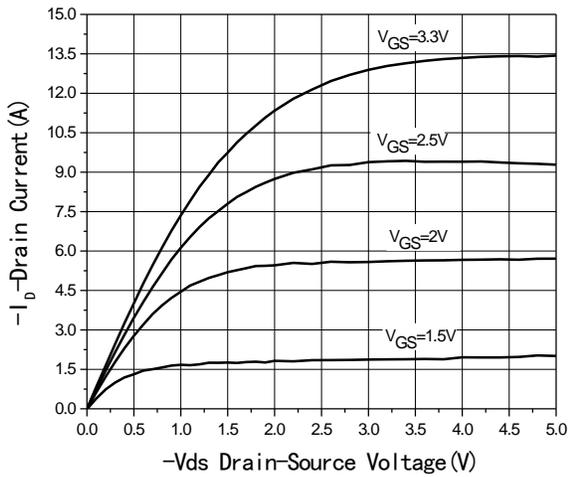


Fig1 Output Characteristics

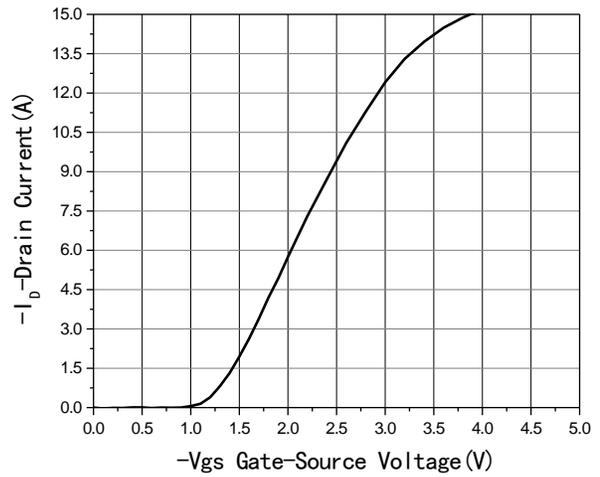


Fig2 Transfer Characteristics

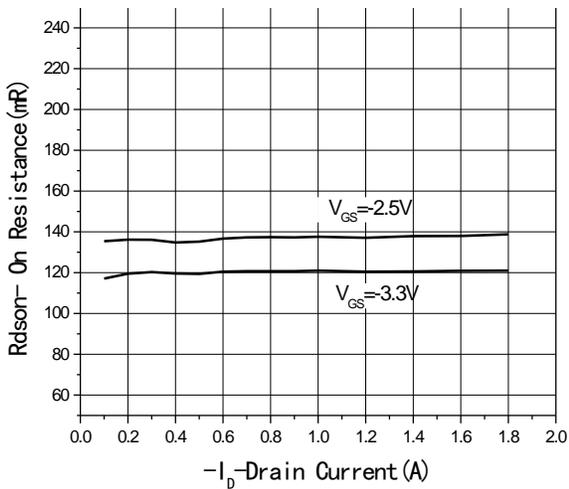


Fig3 $R_{DS(on)}$ -Drain current

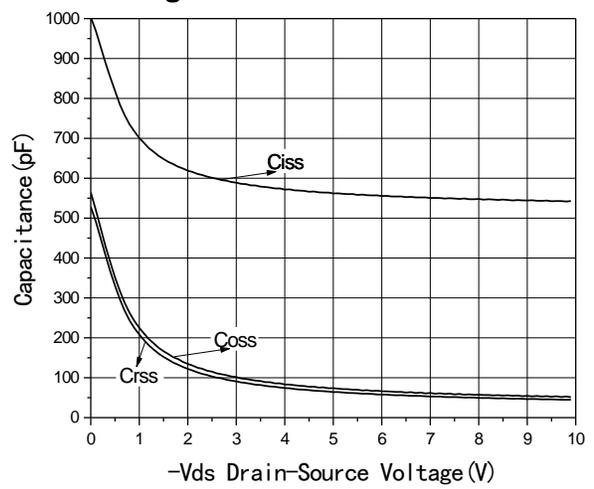


Fig4 Capacitance vs V_{DS}

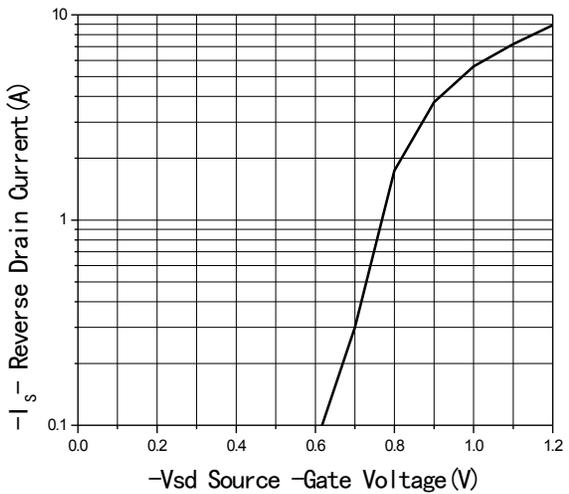


Fig5 Source-Drain Diode Forward

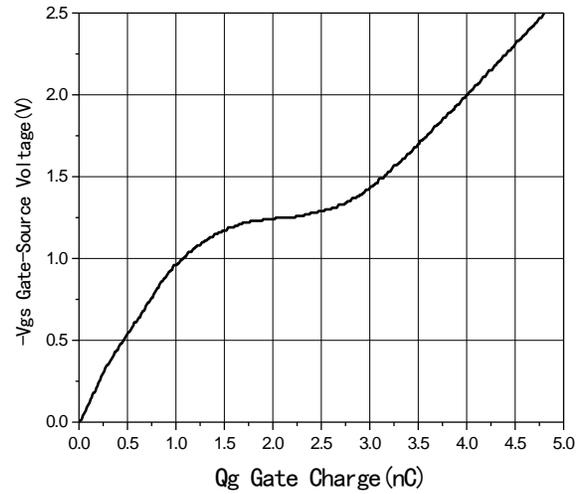


Fig6 Gate Charge

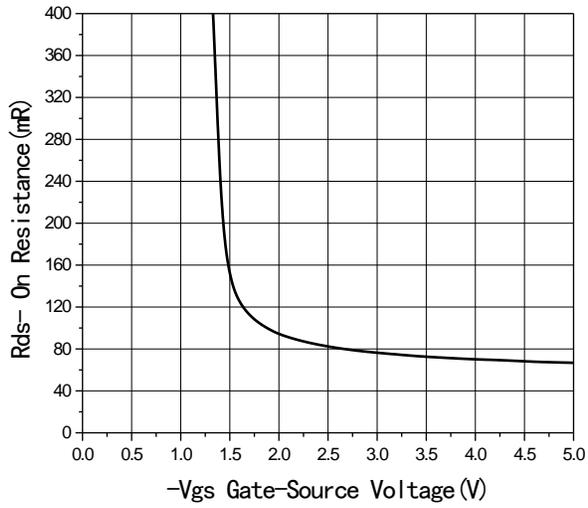


Fig7 Rds-on-Gate Drain voltage

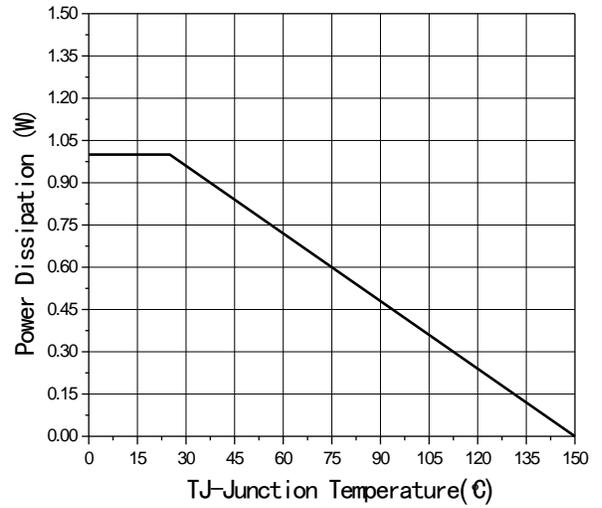
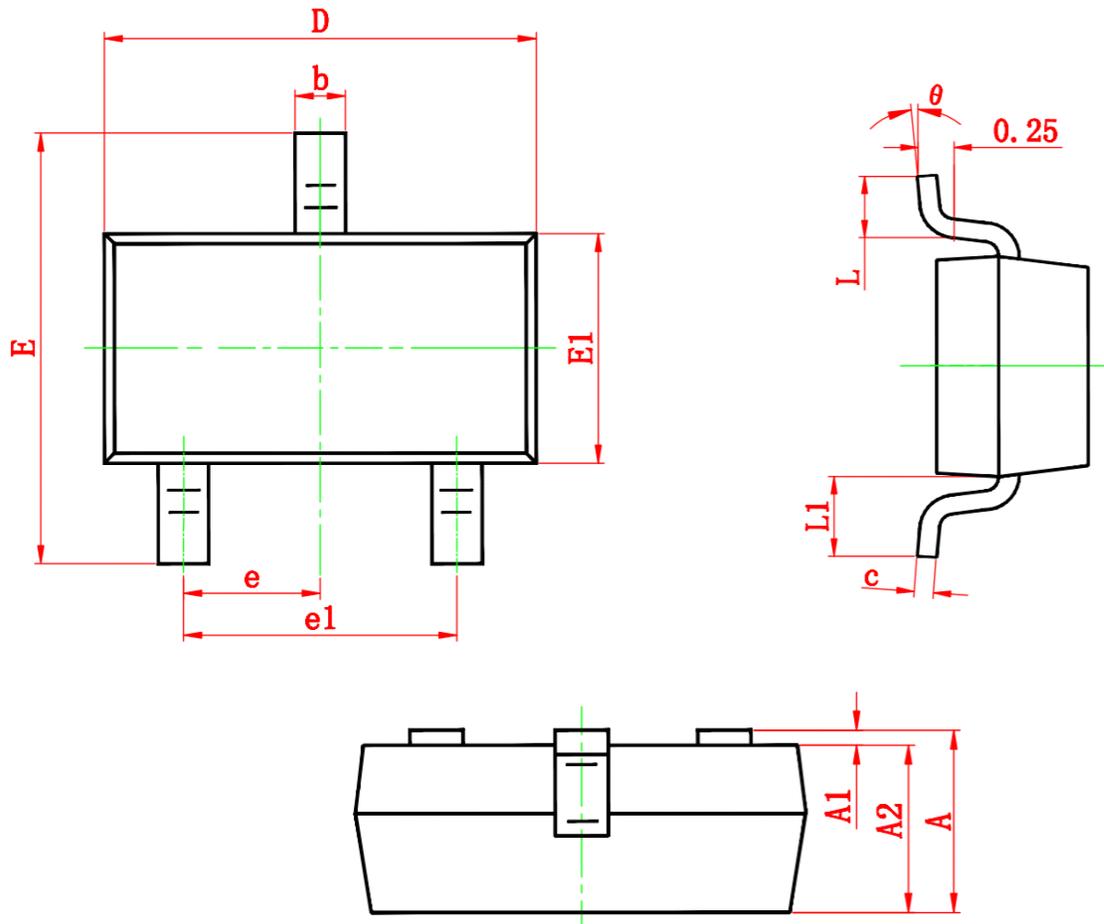


Fig8 Power De-rating

Package Information

- SOT-23



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 2.250 | 2.550 | 0.089 | 0.100 |
| E1 | 1.200 | 1.400 | 0.047 | 0.055 |
| e | 0.950 TYP. | | 0.037 TYP. | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.500 | 0.012 | 0.020 |
| L1 | 0.550 REF. | | 0.022 REF. | |
| θ | 0° | 8° | 0° | 8° |